

**IN THE CLAIMS:**

This listing of claims will replace all prior versions, and listings, of claims in the application.

1. (Previously presented) A light emitting element comprising a plurality of layers interposed between a pair of electrodes opposed to each other,

wherein at least one of the plurality of layers is formed of a layer containing a light emitting material, and

wherein the layer containing the light emitting material is interposed between a layer containing molybdenum oxide and a material having a higher hole transporting property than an electron transporting property, and a layer containing an oxide semiconductor or metal oxide and a material having a higher electron transporting property than a hole transporting property.

2. (Currently Amended) A display device comprising ~~comprises~~ the light emitting element according to claim 1 in a pixel portion.

3. (Previously presented) A light emitting element comprising a plurality of layers interposed between a pair of electrodes opposed to each other,

wherein at least one of the plurality of layers is formed of a layer containing a light emitting material, and

wherein the layer containing the light emitting material is interposed between a layer containing molybdenum oxide and a material having a higher hole transporting property than an electron transporting property, and a layer containing an oxide semiconductor or metal oxide, a

material having a higher electron transporting property than a hole transporting property and a material which can donate an electron to the material having a higher electron transporting property than a hole transporting property.

4. (Currently Amended) A display device comprising ~~comprises~~ the light emitting element according to claim 3 in a pixel portion.

5 (Previously presented) A light emitting element comprising:  
a pair of electrodes; and  
first to third layers sequentially laminated between the pair of electrodes,  
wherein the first layer contains molybdenum oxide and a material having a higher hole transporting property than an electron transporting property,  
wherein the second layer contains a light emitting material, and  
wherein the third layer contains an oxide semiconductor or metal oxide and a material having a higher electron transporting property than a hole transporting property.

6. (Previously presented) A light emitting element according to claim 5, wherein the first layer comprises 4,4'-bis[N-(1-naphthyl)-N-phenylamino]biphenyl.

7. (Currently Amended) A display device comprising ~~comprises~~ the light emitting element according to claim 5 in a pixel portion.

8. (Previously presented) A light emitting element comprising:  
a pair of electrodes; and  
first to third layers sequentially laminated between the pair of electrodes,  
wherein the first layer contains a material having a higher hole transporting property than  
an electron transporting property,  
wherein the second layer contains a light emitting material, and  
wherein the third layer contains an oxide semiconductor or metal oxide, a material having a  
higher electron transporting property than a hole transporting property, and a material which can  
donate an electron to the material having a higher electron transporting property than a hole  
transporting property.

9. (Previously presented) A light emitting element according to claim 8, wherein the first  
layer comprises 4,4'-bis[N-(1-naphthyl)-N-phenylamino]biphenyl.

10. (Currently Amended) A display device comprising ~~comprises~~ the light emitting element  
according to claim 8 in a pixel portion.

11. (Previously presented) A light emitting element comprising:  
a pair of electrodes; and  
first to fourth layers sequentially laminated between the pair of electrodes,  
wherein the first layer contains molybdenum oxide and a material having a higher hole  
transporting property than an electron transporting property,

wherein the second layer contains a light emitting material,

wherein the third layer contains an oxide semiconductor or metal oxide and a material having a higher electron transporting property than a hole transporting property, and

wherein the fourth layer contains an oxide semiconductor or metal oxide, a material having a higher electron transporting property than a hole transporting property, and a material which can donate an electron to the material having a higher electron transporting property than a hole transporting property.

12. (Previously presented) A light emitting element according to claim 11, wherein the first layer comprises 4,4(-bis[N-(1-naphthyl)-N-phenylamino]biphenyl.

13. (Currently Amended) A display device comprising ~~comprises~~ the light emitting element according to claim 11 in a pixel portion.

14. (Previously presented) A light emitting element comprising:

a pair of electrodes; and

first to fourth layers sequentially laminated between the pair of electrodes,

wherein the first layer contains molybdenum oxide and a material having a higher hole transporting property than an electron transporting property,

wherein the second layer contains a light emitting material,

wherein the third layer contains an oxide semiconductor or metal oxide and a material having a higher electron transporting property than a hole transporting property, and

wherein the fourth layer contains a material having a higher electron transporting property than a hole transporting property and a material which can donate an electron to the material having a higher electron transporting property than a hole transporting property.

15. (Previously presented) A light emitting element according to claim 14, wherein the first layer comprises 4,4'-bis[N-(1-naphthyl)-N-phenylamino]biphenyl.

16. (Currently Amended) A display device comprising ~~comprises~~ the light emitting element according to claim 14 in a pixel portion.

17. (Previously presented). A light emitting element comprising:  
a pair of electrodes; and  
first to fourth layers sequentially laminated between the pair of electrodes,  
wherein the first layer contains molybdenum oxide and a material having a higher hole transporting property than an electron transporting property,  
wherein the second layer contains a light emitting material,  
wherein the third layer contains an oxide semiconductor or metal oxide and a material having a higher electron transporting property than a hole transporting property, and  
wherein the fourth layer contains an oxide semiconductor or metal oxide and a material having a higher hole transporting property than an electron transporting property.

18. (Original) A light emitting element according to Claim 17, wherein the first layer and the

fourth layer are formed using the same material.

19. (Previously presented) A light emitting element according to claim 17, wherein the first layer comprises 4,4'-bis[N-(1-naphthyl)-N-phenylamino]biphenyl.

20. (Currently Amended) A display device comprising ~~comprises~~ the light emitting element according to claim 17 in a pixel portion.

21 (Canceled).

22. (Canceled)

23. (Canceled)

24. (Canceled)

25 (Previously presented). A light emitting element comprising:  
a pair of electrodes; and  
first to fifth layers sequentially laminated between the pair of electrodes,  
wherein the first layer contains molybdenum oxide and a material having a higher hole transporting property than an electron transporting property,  
wherein the second layer contains a light emitting material,

wherein the third layer contains an oxide semiconductor or metal oxide and a material having a higher electron transporting property than a hole transporting property,

wherein the fourth layer contains an oxide semiconductor or metal oxide, a material having a higher electron transporting property than a hole transporting property, and a material which can donate an electron to the material having a higher electron transporting property than a hole transporting property, and

wherein the fifth layer contains an oxide semiconductor or metal oxide and a material having a higher hole transporting property than an electron transporting property.

26. (Original) A light emitting element according to Claim 25, wherein the first layer and the fifth layer are formed using the same material.

27. (Previously presented) A light emitting element according to claim 25, wherein the first layer comprises 4,4'-bis[N-(1-naphthyl)-N-phenylamino]biphenyl.

28. (Currently Amended) A display device comprising ~~comprises~~ the light emitting element according to claim 25 in a pixel portion.

29. (Previously presented) A light emitting element comprising:

a pair of electrodes; and

first to fifth layers sequentially laminated between the pair of electrodes,

wherein the first layer contains molybdenum oxide and a material having a higher hole

transporting property than an electron transporting property,

wherein the second layer contains a light emitting material,

wherein the third layer contains an oxide semiconductor or metal oxide and a material having a higher electron transporting property than a hole transporting property,

wherein the fourth layer contains a material having a higher electron transporting property than a hole transporting property and a material which can donate an electron to the material having a higher electron transporting property than a hole transporting property, and

wherein the fifth layer contains an oxide semiconductor or metal oxide and a material having a higher hole transporting property than an electron transporting property.

30. (Original) A light emitting element according to Claim 29, wherein the first layer and the fifth layer are formed using the same material.

31. (Previously presented) A light emitting element according to claim 29, wherein the first layer comprises 4,4'-bis[N-(1-naphthyl)-N-phenylamino]biphenyl.

32. (Currently Amended) A display device comprising ~~comprises~~ the light emitting element according to claim 29 in a pixel portion.